2018년 2월 7일(수), 09:00-10:30 Room A (태백I, 5층)

C. Material Growth & Characterization 분과 [WA1-C] Material Growth and Characterization I

WA1-C-1 09:00-09:30	[초청] 우주방사선에 의한 전자소자 내 결함 생성과 성능 손상 예측을 위한 시뮬레이션 및 실험연구 서유정 ¹ , 다네시와 미시라 ¹ , 강건욱 ² , 김지현 ³ , 박유근 ¹ ¹ 차세대융합기술연구원, 서울대학교, ² 기계공학과, 연세대학교, ³ 화공생명공학과, 고려대학교
WA1-C-2 09:30-09:45	High Quality AlGaN/GaN HEMT Growth on SI-SiC Using High Temperature AlN Nucleation Layer Kyeongjae Lee, Uiho Choi, Jaeyeon Han, Taehoon Jang, Yongjun Nam, and Okhyun Nam Department of Nano-Optical Engineering, Korea Polytechnic University
WA1-C-3 09:45-10:00	Surface Reconstruction and Equilibrium Shape of III-V Compound Semiconductors as a Function of Pressure and Temperature by ab-initio Thermodynamics In Won Yeu ^{1,2} , Gyuseung Han ^{1,2} , Cheol Seong Hwang ² , and Jung-Hae Choi ¹ 1 Center for Electronic Materials, KIST, 2 Department of Materials Science and Engineering, and Inter-university Semiconductor Research Center, Seoul National University
WA1-C-4 10:00-10:15	Growth of AlGaN/GaN Heterostructure with Lattice-Matched Alln(Ga)N Back Barrier Jeong-Gil Kim, Seung-Hyeon Kang, Jun-Hyeok Lee, Ki-Sik Im, Dong-Hyeok Son, Jung-Min Ju, Yong-Soo Lee, and Jung-Hee Lee School of Electronics Engineering, Kyungpook National University
WA1-C-5 10:15-10:30	Prediction of the Atomic Configuration and Electronic Properties of Ga(As,Sb) Solid Solution Using Cluster Expansion Method Gyuseung Han ^{1,2} , In Won Yeu ^{1,2} , Mahesh Chandran ³ , Seung Cheol Lee ³ , Cheol Seong Hwang ² , and Jung-Hae Choi ¹ 1 Center for Electronic Materials, KIST, 2 Department of Materials Science and Engineering, and Inter-university Semiconductor Research Center, Seoul National University, 3 Indo-Korea Science and Technology Center